

# SKM 100GB128D



**SEMITRANS® 2**

## SPT IGBT Module

**SKM 100GB128D**

### Features

- SPT = Soft-Punch-Through technology
- $V_{CEsat}$  with positive temperature coefficient
- High short circuit capability, self limiting to  $6 \times I_C$

### Typical Applications

- AC inverter drives
- UPS
- Electronic welders at  $f_{sw}$  up to 20 kHz



**GB**

Absolute Maximum Ratings		$T_c = 25\text{ °C}$ , unless otherwise specified			
Symbol	Conditions	Values			Units
<b>IGBT</b>					
$V_{CES}$	$T_j = 25\text{ °C}$	1200			V
$I_C$	$T_j = 150\text{ °C}$	$T_c = 25\text{ °C}$	145		A
		$T_c = 80\text{ °C}$	105		A
$I_{CRM}$	$I_{CRM} = 2 \times I_{Cnom}$	150			A
$V_{GES}$		$\pm 20$			V
$t_{psc}$	$V_{CC} = 600\text{ V}; V_{GE} \leq 20\text{ V}; T_j = 125\text{ °C}$ $V_{CES} < 1200\text{ V}$	10			$\mu\text{s}$
<b>Inverse Diode</b>					
$I_F$	$T_j = 150\text{ °C}$	$T_{case} = 25\text{ °C}$	95		A
		$T_{case} = 80\text{ °C}$	65		A
$I_{FRM}$	$I_{FRM} = 2 \times I_{Fnom}$	150			A
$I_{FSM}$	$t_p = 10\text{ ms}; \text{sin.}$	$T_j = 150\text{ °C}$	720		A
<b>Module</b>					
$I_{t(RMS)}$		200			A
$T_{vj}$		- 40... + 150			$^{\circ}\text{C}$
$T_{stg}$		- 40... + 125			$^{\circ}\text{C}$
$V_{isol}$	AC, 1 min.	4000			V

Characteristics		$T_c = 25\text{ °C}$ , unless otherwise specified			
Symbol	Conditions	min.	typ.	max.	Units
<b>IGBT</b>					
$V_{GE(th)}$	$V_{GE} = V_{CE}; I_C = 3\text{ mA}$	4,5	5,5	6,45	V
$I_{CES}$	$V_{GE} = 0\text{ V}; V_{CE} = V_{CES}$	$T_j = 25\text{ °C}$	0,1	0,3	mA
		$T_j = 125\text{ °C}$	0,9	1,05	V
$V_{CE0}$		$T_j = 25\text{ °C}$	1	1,15	V
		$T_j = 125\text{ °C}$	0,9	1,05	V
$r_{CE}$	$V_{GE} = 15\text{ V}$	$T_j = 25\text{ °C}$	13	16	$\text{m}\Omega$
		$T_j = 125\text{ °C}$	16	20	$\text{m}\Omega$
$V_{CE(sat)}$	$I_{Cnom} = 75\text{ A}; V_{GE} = 15\text{ V}$	$T_j = 25\text{ °C}_{chiplev.}$	1,9	2,35	V
		$T_j = 125\text{ °C}_{chiplev.}$	2,1	2,55	V
$C_{ies}$	$V_{CE} = 25; V_{GE} = 0\text{ V}$	$f = 1\text{ MHz}$	6,2		nF
$C_{oes}$			0,74		nF
$C_{res}$			0,71		nF
$Q_G$	$V_{GE} = -8\text{ V} - +20\text{ V}$	860			nC
$R_{Gint}$	$T_j = 25\text{ °C}$	5			$\Omega$
$t_{d(on)}$	$R_{Gon} = 4,7\ \Omega$	$V_{CC} = 600\text{ V}$ $I_C = 75\text{ A}$	175		ns
$t_r$			38		ns
$E_{on}$			9		mJ
$t_{d(off)}$	$R_{Goff} = 4,7\ \Omega$	$T_j = 125\text{ °C}$ $V_{GE} = \pm 15\text{ V}$	370		ns
$t_f$			65		ns
$E_{off}$			7,5		mJ
$R_{th(j-c)}$	per IGBT	0,21			K/W



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Characteristics			min.	typ.	max.	Units
<b>Inverse Diode</b>						
$V_F = V_{EC}$	$I_{Fnom} = 75 \text{ A}; V_{GE} = 0 \text{ V}$	$T_j = 25 \text{ }^\circ\text{C}_{chiplev.}$		2	2,5	V
		$T_j = 125 \text{ }^\circ\text{C}_{chiplev.}$		1,8		V
$V_{F0}$		$T_j = 25 \text{ }^\circ\text{C}$		1,1	1,2	V
$r_F$		$T_j = 25 \text{ }^\circ\text{C}$		12	17,3	mΩ
$I_{RRM}$	$I_F = 75 \text{ A}$	$T_j = 125 \text{ }^\circ\text{C}$		88		A
$Q_{rr}$	$di/dt = 2800 \text{ A}/\mu\text{s}$			13		μC
$E_{rr}$	$V_{GE} = -15 \text{ V}; V_{CC} = 600 \text{ V}$			3,9		mJ
$R_{th(j-c)D}$	per diode				0,5	K/W
<b>Module</b>						
$L_{CE}$					30	nH
$R_{CC+EE}$	res., terminal-chip	$T_{case} = 25 \text{ }^\circ\text{C}$		0,75		mΩ
		$T_{case} = 125 \text{ }^\circ\text{C}$		1		mΩ
$R_{th(c-s)}$	per module				0,05	K/W
$M_s$	to heat sink M6			3	5	Nm
$M_t$	to terminals M5			2,5	5	Nm
w					160	g

This is an electrostatic discharge sensitive device (ESDS), international standard IEC 60747-1, Chapter IX.

This technical information specifies semiconductor devices but promises no characteristics. No warranty or guarantee expressed or implied is made regarding delivery, performance or suitability.

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## SPT IGBT Module

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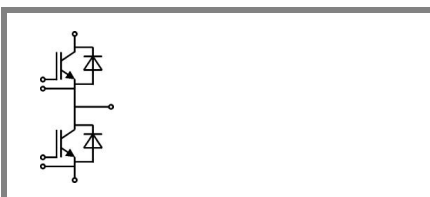
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$Z_{th}$		Conditions	Values	Units
<b><math>Z_{th(j-c)I}</math></b>				
$R_{\theta j-c}$	$i = 1$		114	mk/W
$R_{\theta j-c}$	$i = 2$		71	mk/W
$R_{\theta j-c}$	$i = 3$		22	mk/W
$R_{\theta j-c}$	$i = 4$		3	mk/W
$\tau_{\theta j-c}$	$i = 1$		0,054	s
$\tau_{\theta j-c}$	$i = 2$		0,0115	s
$\tau_{\theta j-c}$	$i = 3$		0,0012	s
$\tau_{\theta j-c}$	$i = 4$		0,001	s
<b><math>Z_{th(j-c)D}</math></b>				
$R_{\theta j-c}$	$i = 1$		300	mk/W
$R_{\theta j-c}$	$i = 2$		160	mk/W
$R_{\theta j-c}$	$i = 3$		35,5	mk/W
$R_{\theta j-c}$	$i = 4$		4,5	mk/W
$\tau_{\theta j-c}$	$i = 1$		0,054	s
$\tau_{\theta j-c}$	$i = 2$		0,0071	s
$\tau_{\theta j-c}$	$i = 3$		0,0017	s
$\tau_{\theta j-c}$	$i = 4$		0,005	s



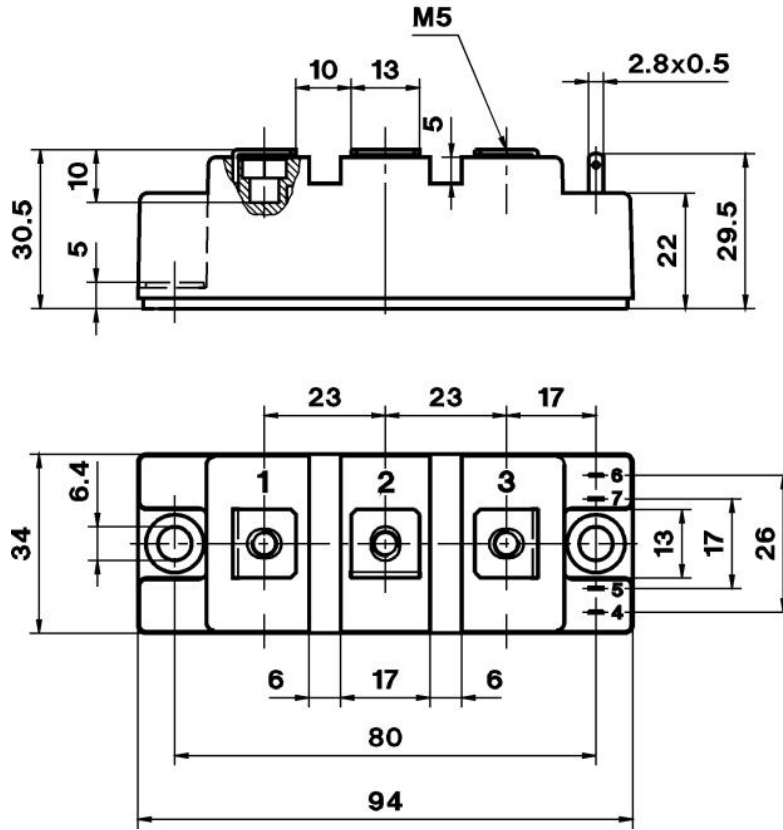
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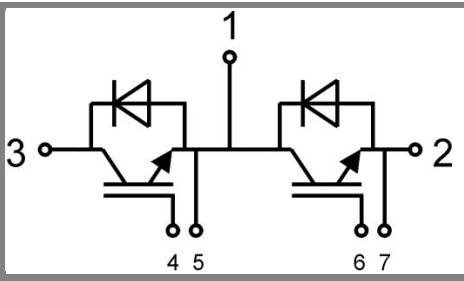
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